CHANGE NOTIFICATION



June 28, 2013

Dear Sir/Madam: PCN# 062813

Subject: Notification of Change to LTC3612, LTC3614, LTC3615, LTC3616

Please be advised that Linear Technology Corporation has made minor changes to the LTC3612, LTC3614, LTC3615/-1 and LTC3616 family of monolithic synchronous buck converters. A minor mask revision was made to improve application robustness and efficiency at low switching frequencies. The original production silicon turns off the low side switch too early in some applications, which leads to current flow in the body diode. The revised silicon avoids this limitation and improves efficiency in low frequency (<600 KHz) Burst Mode operation. Further, the external Soft Start function was improved to keep the output voltage in regulation during fast drops in input voltage.

In addition, in order to improve manufacturability, the specification for the minimum top switch current limit at 100% duty cycle will be reduced slightly for the LTC3612, LTC3614 and LTC3616 as shown in the attached redlined specifications. The LTC3615/LTC3615-1 specifications and datasheet are unchanged.

These changes were qualified by performing characterization over the full operating junction temperature range and through rigorous engineering bench evaluations. In addition, each product successfully completed 1000 hours of HTOL stress. Product built using the new die and tested to the updated specification will be shipped with a datecode of approximately 1348.

Should you have any further questions, please feel free to contact me at 408-432-1900 ext. 2077, or by email at <u>JASON.HU@LINEAR.COM</u>. If I do not hear from you by August 29th, 2013, we will consider this change to be approved by your company.

Sincerely,

Jason Hu Quality Assurance Engineer

ELECTRICAL CHARACTERISTICS The ullet denotes the specifications which apply over the full operating junction temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_{IN} = 3.3V$, RT/SYNC = SV_{IN} , unless otherwise specified (Note 2).

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{IN}	Operating Voltage Range		•	2.25		5.5	V
V _{UVLO}	Undervoltage Lockout Threshold	SV _{IN} Ramping Down SV _{IN} Ramping Up	•	1.7		2.25	V
V _{FB}	Feedback Voltage Internal Reference	(Notes 3, 4) V _{TRACK/SS} = SV _{IN} , V _{DDR} = 0V 0°C < T _J < 85°C -40°C < T _J < 125°C	•	0.594 0.591	0.6	0.606 0.609	V
	Feedback Voltage External Reference (Note 7)	(Notes 3, 4) V _{TRACK/SS} = 0.3V, V _{DDR} = SV _{IN}		0.289	0.3	0.311	V
		(Notes 3, 4) V _{TRACK/SS} = 0.5V, V _{DDR} = SV _{IN}		0.489	0.5	0.511	V
I _{FB}	Feedback Input Current	V _{FB} = 0.6V	•			±30	nA
$\Delta V_{LINEREG}$	Line Regulation	SV _{IN} = PV _{IN} = 2.25V to 5.5V (Notes 3, 4) TRACK/SS = SV _{IN}	•			0.2	%/V
$\Delta V_{LOADREG}$	Load Regulation	ITH from 0.5V to 0.9V (Notes 3, 4) V _{ITH} = SV _{IN} (Note 5)				0.25 2.6	% %
Is	Active Mode	V _{FB} = 0.5 V, V _{MODE} = SV _{IN} (Note 6)			1100		μА
	Sleep Mode	V _{FB} = 0.7V, V _{MODE} = 0V, ITH = SV _{IN} (Note 5)			70	100	μА
		V _{FB} = 0.7V, V _{MODE} = 0V (Note 4)			120	160	μА
	Shutdown	SV _{IN} = PV _{IN} = 5.5V, V _{RUN} = 0V			0.1	1	μА
R _{DS(ON)}	Top Switch On-Resistance	PV _{IN} = 3.3V (Note 10)			70		mΩ
	Bottom Switch On-Resistance	PV _{IN} = 3.3V (Note 10)			45		mΩ
I _{LIM}	Top Switch Current Limit	Sourcing (Note 8), V _{FB} = 0.5V Duty Cycle <35% Duty Cycle = 100%		5.2 A 3.7	6	6.8	A A
	Bottom Switch Current Limit	Sinking (Note 8), V _{FB} = 0.7V, Forced Continuous Mode		-3	-4	-5	А
9m(EA)	Error Amplifier Transconductance	-5μA < I _{ITH} < 5μA (Note 4)			200		μS
I _{EAO}	Error Amplifier Max Output Current	(Note 4)			±30		μА
t _{SS}	Internal Soft-Start Time	V _{FB} from 0.06V to 0.54V, TRACK/SS = SV _{IN}		0.65	1	1.5	ms
V _{TRACK/SS}	Enable Internal Soft-Start	(Note 7)		0.62			V
t _{TRACK/SS_DIS}	Soft-Start Discharge Time at Start-Up			70			μs
Ron(track/ss_dis)	TRACK/SS Pull-Down Resistor at Start-Up					200	Ω
fosc	Oscillator Frequency	RT/SYNC = 370k	•	0.8	1	1.2	MHz
	Internal Oscillator Frequency	V _{RT/SYNC} = SV _{IN}	•	1.8	2.25	2.7	MHz
f _{SYNC}	Synchronization Frequency			0.3		4	MHz
V _{RT/SYNC}	SYNC Level High			1.2			V
	SYNC Level Low					0.3	V
I _{SW(LKG)}	Switch Leakage Current	SV _{IN} = PV _{IN} = 5.5V, V _{RUN} = 0V			0.1	1	μА
V _{DDR}	DDR Option Enable Voltage			SV _{IN} - 0.3			V
V _{MODE} (Note 9)	Internal Burst Mode Operation					0.3	V
	Pulse-Skipping Mode			SV _{IN} - 0.3			V
	Forced Continuous Mode			1.1		SV _{IN} • 0.58	V
	External Burst Mode Operation			0.45		0.8	V



ELECTRICAL CHARACTERISTICS The ullet denotes the specifications which apply over the full operating junction temperature range, otherwise specifications are at $T_A = 25^{\circ}$ C. $V_{IN} = 3.3$ V, RT/SYNC = SV_{IN} unless otherwise specified (Notes 1, 2, 11).

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{IN}	Operating Voltage Range		•	2.25		5.5	V
V _{UVLO}	Undervoltage Lockout Threshold	SV _{IN} Ramping Down SV _{IN} Ramping Up	•	1.7		2.25	V V
V _{FB}	Feedback Voltage Internal Reference	(Note 3) V _{TRACK} = SV _{IN} , V _{DDR} = 0V 0°C < T _J < 85°C -40°C < T _J < 125°C	•	0.594 0.591	0.6	0.606 0.609	V
	Feedback Voltage External Reference (Note 7)	(Note 3) V _{TRACK} = 0.3V, V _{DDR} = SV _{IN}		0.288	0.300	0.312	V
		(Note 3) V _{TRACK} = 0.5V, V _{DDR} = SV _{IN}		0.488	0.500	0.512	V
I _{FB}	Feedback Input Current	V _{FB} = 0.6V	•			±30	nA
ΔV _{LINEREG}	Line Regulation	SV _{IN} = PV _{IN} = 2.25V to 5.5V (Notes 3, 4) TRACK/SS = SV _{IN}	•			0.2	%/V
$\Delta V_{LOADREG}$	Load Regulation	ITH from 0.5V to 0.8V (Notes 3, 4) V _{ITH} = SV _{IN} (Note 5)				0.25 2.6	% %
Is	Active Mode Supply Current	V _{FB} = 0.5V, V _{MODE} = SV _{IN} (Note 6)			1100		μА
	Sleep Mode Supply Current	V_{FB} = 0.7V, V_{MODE} = 0V, ITH = SV_{IN} (Note 5)			75	100	μА
		V _{FB} = 0.7V, V _{MODE} = 0V (Note 4)			130	175	μА
	Shutdown Current	$SV_{IN} = PV_{IN} = 5.5V$, $V_{RUN} = 0V$			0.1	1	μА
R _{DS(ON)}	Top Switch On-Resistance	PV _{IN} = 3.3V (Note 10)			35		mΩ
	Bottom Switch On-Resistance	PV _{IN} = 3.3V (Note 10)			25		mΩ
I _{LIM}	Top Switch Current Limit	Sourcing (Note 8), V _{FB} = 0.5V Duty Cycle <35% Duty Cycle = 100%		7.5 -5.3′ 5	9	10.5	A A
	Bottom Switch Current Limit	Sinking (Note 8), V _{FB} = 0.7V, Forced Continuous Mode		-6	-8	-11	А
g _{m(EA)}	Error Amplifier Transconductance	-5μA < I _{ITH} < 5μA (Note 4)			200		μS
I _{EAO}	Error Amplifier Maximum Output Current	(Note 4)			±30		μА
t _{SS}	Internal Soft-Start Time	V _{FB} from 0.06V to 0.54V, TRACK/SS = SV _{IN}		0.65	1.2	1.9	ms
V _{TRACK/SS}	Enable Internal Soft-Start	(Note 7)		0.62			V
t _{TRACK/SS_DIS}	Soft-Start Discharge Time at Start-Up			60			μs
R _{ON(TRACK/SS_DIS)}	TRACK/SS Pull-Down Resistor at Start-Up					200	Ω
f _{osc}	Oscillator Frequency	RT/SYNC = 370k	•	0.8	1	1.2	MHz
	Internal Oscillator Frequency	V _{RT/SYNC} = SV _{IN}	•	1.8	2.25	2.7	MHz
f _{SYNC}	Synchronization Frequency Range			0.3		4	MHz
V _{RT/SYNC}	SYNC Input Threshold High			1.2			V
	SYNC Input Threshold Low					0.3	V
I _{SW(LKG)}	Switch Leakage Current	$SV_{IN} = PV_{IN} = 5.5V$, $V_{RUN} = 0V$			0.1	1	μА
V _{DDR}	DDR Option Enable Voltage			SV _{IN} - 0.3			V
V _{MODE} (Note 9)	Internal Burst Mode Operation					0.3	V
	Pulse-Skipping Mode			SV _{IN} - 0.3			V
	Forced Continuous Mode		_	1.1		SV _{IN} • 0.58	V
	External Burst Mode Operation			0.45		0.8	V



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SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{IN}	Operating Voltage Range		•	2.25		5.5	V
V _{UVLO}	Undervoltage Lockout Threshold	SV _{IN} Ramping Down SV _{IN} Ramping Up	•	1.7		2.25	V
V _{FB}	Feedback Voltage Internal Reference	(Note 3) V _{TRACK} = SV _{IN} , V _{DDR} = 0V 0°C < T _J < 85°C -40°C < T _J < 125°C		0.594 0.591	0.6	0.606 0.609	V
	Feedback Voltage External Reference (Note 7)	(Note 3) V _{TRACK} = 0.3V, V _{DDR} = SV _{IN}		0.275	0.300	0.325	V
		(Note 3) V _{TRACK} = 0.5V, V _{DDR} = SV _{IN}		0.475	0.500	0.525	V
I _{FB}	Feedback Input Current	V _{FB} = 0.6V	•			±30	nA
ΔV _{LINEREG}	Line Regulation	SV _{IN} = PV _{IN} = 2.25V to 5.5V (Notes 3, 4) TRACK/SS = SV _{IN}	•			0.2	%/V
$\Delta V_{LOADREG}$	Load Regulation	ITH from 0.5V to 0.9V (Notes 3, 4) V _{ITH} = SV _{IN} (Note 5)				0.25 2.6	% %
Is	Active Mode	V _{FB} = 0.5V, V _{MODE} = SV _{IN} (Note 6)			1100		μА
	Sleep Mode	V_{FB} = 0.7V, V_{MODE} = 0V, ITH = SV_{IN} (Note 5)			75	100	μА
		V _{FB} = 0.7V, V _{MODE} = 0V (Note 4)			130	175	μА
	Shutdown	$SV_{IN} = PV_{IN} = 5.5V$, $V_{RUN} = 0V$			0.1	1	μА
R _{DS(ON)}	Top Switch On-Resistance	PV _{IN} = 3.3V (Note 10)			35		mΩ
	Bottom Switch On-Resistance	PV _{IN} = 3.3V (Note 10)	\perp		25		mΩ
I _{LIM}	Top Switch Current Limit	Sourcing (Note 8), V _{FB} = 0.5V Duty Cycle <35% Duty Cycle = 100%		10.5 -8′ 7.6	12	13.5	A A
	Bottom Switch Current Limit	Sinking (Note 8), V _{FB} = 0.7V, Forced Continuous Mode		-6	-8	-11	A
g _{m(EA)}	Error Amplifier Transconductance	-5μA < I _{ITH} < 5μA (Note 4)			200		μS
I _{EAO}	Error Amplifier Maximum Output Current	(Note 4)			±30		μА
t _{SS}	Internal Soft-Start Time	V _{FB} from 0.06V to 0.54V, TRACK/SS = SV _{IN}		0.65	1.2	1.9	ms
V _{TRACK/SS}	Enable Internal Soft-Start	(Note 7)		0.62			V
t _{TRACK/SS_DIS}	Soft-Start Discharge Time at Start-Up			60			μs
R _{ON(TRACK/SS_DIS)}	TRACK/SS Pull-Down Resistor at Start-Up					200	Ω
f _{osc}	Oscillator Frequency	RT/SYNC = 370k	•	0.8	1	1.2	MHz
	Internal Oscillator Frequency	V _{RT/SYNC} = SV _{IN}	•	1.8	2.25	2.7	MHz
f _{SYNC}	Synchronization Frequency Range			0.3		4	MHz
V _{RT/SYNC}	SYNC Level High			1.2			V
	SYNC Level Low		\perp			0.3	V
I _{SW(LKG)}	Switch Leakage Current	$SV_{IN} = PV_{IN} = 5.5V$, $V_{RUN} = 0V$	_		0.1	1	μА
V _{DDR}	DDR Option Enable Voltage		\perp	SV _{IN} - 0.3			V
V _{MODE} (Note 9)	Internal Burst Mode Operation		\perp			0.3	V
	Pulse-Skipping Mode			SV _{IN} - 0.3			V
	Forced Continuous Mode			1.1		SV _{IN} • 0.58	V
	External Burst Mode Operation			0.45		0.8	V



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